

ZENER DIODES

RD2.0E to RD120E

500 mW PLANAR TYPE SILICON ZENER DIODES

The RD2.0E to RD120E are zener diodes with an allowable dissipation of 500 mW and a planar type glass sealed DHD (double heatsink diode) structure.

FEATURES

- The zener voltage series has a wide voltage range of 2 V to 120 V and is ideal for standardization.
- The E24 series is employed for the zener voltage nominal value.

ORDERING INFORMATION

Any of the B1 to B7 voltage classifications are available for customers who request the B grade product of the RD2.0E to RD39E.

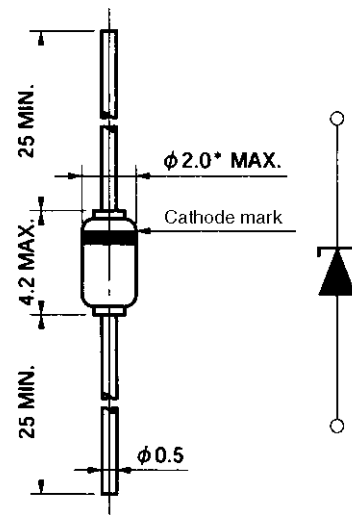
APPLICATIONS

- Zener voltage and constant-current circuit
- Waveform clipper circuit and limiter circuit
- Surge absorption circuit

ABSOLUTE MAXIMUM RATINGS (Ta = 25°C)

Parameter	Symbol	Ratings	Unit	Remarks
Power dissipation	P	500	mW	
Junction temperature	T _j	175	°C	
Forward current	I _F	200	mA	
Storage temperature	T _{stg}	–65 to +175	°C	
Surge reverse power	P _{RSM}	100 (t = 100 μs)	W	Refer to Figure 6.

PACKAGE DRAWING (UNIT: mm)



Marking color: Black
JEDEC: DO-35

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ELECTRICAL CHARACTERISTICS (Ta = 25°C)

Type Number	Suffix	Zener Voltage Vz (V) ^{Note 1}			Dynamic Impedance Zz (Ω) ^{Note 2}		Knee Dynamic Impedance Zzk (Ω) ^{Note 2}		Reverse Current Ir (μA)		Zener Voltage Temperature Coefficient γz (mV/°C)	
		MIN.	MAX.	Iz (mA)	MAX.	Iz (mA)	MAX.	Iz (mA)	MAX.	Iz (mA)	MAX.	Iz (mA)
RD2.0E	B	1.88	2.20	20	140	20	2000	1	120	0.5	-1.0	20
	B1	1.88	2.10									
	B2	2.02	2.20									
RD2.2E	B	2.12	2.41	20	120	20	2000	1	120	0.7	-1.5	20
	B1	2.12	2.30									
	B2	2.22	2.41									
RD2.4E	B	2.33	2.63	20	100	20	2000	1	120	1.0	-1.5	20
	B1	2.33	2.52									
	B2	2.43	2.63									
RD2.7E	B	2.54	2.91	20	100	20	1000	1	100	1.0	-1.5	20
	B1	2.54	2.75									
	B2	2.69	2.91									
RD3.0E	B	2.85	3.22	20	80	20	1000	1	50	1.0	-2.0	20
	B1	2.85	3.07									
	B2	3.01	3.22									
RD3.3E	B	3.16	3.53	20	70	20	1000	1	20	1.0	-2.0	20
	B1	3.16	3.38									
	B2	3.32	3.53									
RD3.6E	B	3.47	3.83	20	60	20	1000	1	10	1.0	-2.0	20
	B1	3.47	3.68									
	B2	3.62	3.83									
RD3.9E	B	3.77	4.14	20	50	20	1000	1	5	1.0	-2.0	20
	B1	3.77	3.98									
	B2	3.92	4.14									
RD4.3E	B	4.05	4.53	20	40	20	1000	1	5	1.0	-1.5	20
	B1	4.05	4.26									
	B2	4.20	4.40									
	B3	4.34	4.53									
RD4.7E	B	4.47	4.91	20	25	20	900	1	5	1.0	-1.0	20
	B1	4.47	4.65									
	B2	4.59	4.77									
	B3	4.71	4.91									
RD5.1E	B	4.85	5.35	20	20	20	800	1	5	1.5	0.5	20
	B1	4.85	5.03									
	B2	4.97	5.18									
	B3	5.12	5.35									
RD5.6E	B	5.29	5.88	20	13	20	500	1	5	2.5	1.5	20
	B1	5.29	5.52									
	B2	5.46	5.70									
	B3	5.64	5.88									
RD6.2E	B	5.81	6.40	20	10	20	300	1	5	3.0	2.0	20
	B1	5.81	6.06									
	B2	5.99	6.24									
	B3	6.16	6.40									

Type Number	Suffix	Zener Voltage V _Z (V) ^{Note 1}			Dynamic Impedance Z _Z (Ω) ^{Note 2}		Knee Dynamic Impedance Z _{ZK} (Ω) ^{Note 2}		Reverse Current I _R (μA)		Zener Voltage Temperature Coefficient γ _Z (mV/°C)	
		MIN.	MAX.	I _Z (mA)	MAX.	I _Z (mA)	MAX.	I _Z (mA)	MAX.	I _Z (mA)	MAX.	I _Z (mA)
RD6.8E	B	6.32	6.97	20	8	20	150	0.5	2	3.5	2.5	20
	B1	6.32	6.59									
	B2	6.52	6.79									
	B3	6.70	6.97									
RD7.5E	B	6.88	7.64	20	8	20	120	0.5	0.5	4.0	3.0	20
	B1	6.88	7.19									
	B2	7.11	7.41									
	B3	7.33	7.64									
RD8.2E	B	7.56	8.41	20	8	20	120	0.5	0.5	5.0	4.0	20
	B1	7.56	7.90									
	B2	7.82	8.15									
	B3	8.07	8.41									
RD9.1E	B	8.33	9.29	20	8	20	120	0.5	0.5	6.0	4.5	20
	B1	8.33	8.70									
	B2	8.61	8.99									
	B3	8.89	9.29									
RD10E	B	9.19	10.30	20	8	20	120	0.5	0.2	7.0	5.5	20
	B1	9.19	9.59									
	B2	9.48	9.90									
	B3	9.82	10.30									
RD11E	B	10.18	11.26	10	10	10	120	0.5	0.2	8.0	6.5	10
	B1	10.18	10.63									
	B2	10.50	10.95									
	B3	10.82	11.26									
RD12E	B	11.13	12.30	10	12	10	110	0.5	0.2	9.0	7.5	10
	B1	11.13	11.63									
	B2	11.50	11.92									
	B3	11.80	12.30									
RD13E	B	12.18	13.62	10	14	10	110	0.5	0.2	10	8.5	10
	B1	12.18	12.71									
	B2	12.59	13.16									
	B3	13.03	13.62									
RD15E	B	13.48	15.02	10	16	10	110	0.5	0.2	11	10	10
	B1	13.48	14.09									
	B2	13.95	14.56									
	B3	14.42	15.02									
RD16E	B	14.87	16.50	10	18	10	150	0.5	0.2	12	11	10
	B1	14.87	15.50									
	B2	15.33	15.93									
	B3	15.79	16.50									
RD18E	B	16.34	18.30	10	23	10	150	0.5	0.2	13	13	10
	B1	16.34	17.06									
	B2	16.90	17.67									
	B3	17.51	18.30									

Type Number	Suffix	Zener Voltage V _z (V) ^{Note 1}			Dynamic Impedance Z _z (Ω) ^{Note 2}		Knee dynamic Impedance Z _{zk} (Ω) ^{Note 2}		Reverse Current I _r (μA)		Zener Voltage Temperature Coefficient γ _z (mV/°C)	
		MIN.	MAX.	I _z (mA)	MAX.	I _z (mA)	MAX.	I _z (mA)	MAX.	I _z (mA)	MAX.	I _z (mA)
RD20E	B	18.11	20.72	10	28	10	200	0.5	0.2	15	15	10
	B1	18.11	18.92									
	B2	18.73	19.57									
	B3	19.38	20.22									
	B4	19.88	20.72									
RD22E	B	20.23	22.61	5	30	5	200	0.5	0.2	17	17	5
	B1	20.23	21.08									
	B2	20.76	21.65									
	B3	21.22	22.09									
	B4	21.68	22.61									
RD24E	B	22.26	24.81	5	35	5	200	0.5	0.2	19	19	5
	B1	22.26	23.12									
	B2	22.75	23.73									
	B3	23.29	24.27									
	B4	23.81	24.81									
RD27E	B	24.26	27.64	5	45	5	250	0.5	0.2	21	21	5
	B1	24.26	25.52									
	B2	24.97	26.26									
	B3	25.63	26.95									
	B4	26.29	27.64									
RD30E	B	26.99	30.51	5	55	5	250	0.5	0.2	23	24	5
	B1	26.99	28.39									
	B2	27.70	29.13									
	B3	28.36	29.82									
	B4	29.02	30.51									
RD33E	B	29.68	33.11	5	65	5	250	0.5	0.2	25	26	5
	B1	29.68	31.22									
	B2	30.32	31.88									
	B3	30.90	32.50									
	B4	31.49	33.11									
RD36E	B	32.14	35.77	5	75	5	250	0.5	0.2	27	29	5
	B1	32.14	33.79									
	B2	32.79	34.49									
	B3	33.40	35.13									
	B4	34.01	34.77									
R39E	B	34.68	40.80	5	85	5	250	0.5	0.2	30	32	5
	B1	34.68	36.47									
	B2	35.36	37.19									
	B3	36.00	37.85									
	B4	36.63	38.52									
	B5	37.36	39.29									
	B6	38.14	40.11									
	B7	38.94	40.80									

- Notes**
1. The zener voltage (V_z) of the B and B1 to B7 grades is tested for 40 ms after power ON.
 2. The operation resistance (Z_z, Z_{zk}) is tested by superimposing a micro AC on the standard current (I_z).
 3. The B grade is a composition of the B1 to B7 grades. Any of the B1 to B7 voltage classifications are available for customers who request the B grade product.

Type Number	Suffix	Zener Voltage V _Z (V) ^{Note 1}			Dynamic Impedance Z _Z (Ω) ^{Note 2}		Reverse Current I _R (μA)		Zener Voltage Temperature Coefficient γ _Z (mV/°C)	
		MIN.	MAX.	I _Z (mA)	MAX.	I _Z (mA)	MAX.	I _Z (mA)	MAX.	I _Z (mA)
RD43E	B	40	45	5	90	5	0.2	33	37	5
RD47E	B	44	49	5	90	5	0.2	36	41	5
RD51E	B	48	54	5	110	5	0.2	39	45	5
RD56E	B	53	60	5	110	5	0.2	43	51	5
RD62E	B	58	66	2	200	2	0.2	47	56	2
RD68E	B	64	72	2	200	2	0.2	52	62	2
RD75E	B	70	79	2	300	2	0.2	57	69	2
RD82E	B	77	87	2	300	2	0.2	63	76	2
RD91E	B	85	96	2	400	2	0.2	69	85	2
RD100E	B	94	106	2	400	2	0.2	76	95	2
RD110E	B	104	116	1	750	1	0.2	84	105	1
RD120E	B	114	126	1	900	1	0.2	91	115	1

Notes 1. The zener voltage (V_Z) is tested for 40 ms after power ON.

2. The operation resistance (Z_Z) is tested by superimposing a micro AC on the standard current (I_Z).

TYPICAL CHARACTERISTICS ($T_a = 25^\circ\text{C}$)

Figure 1. P vs. T_a Rating

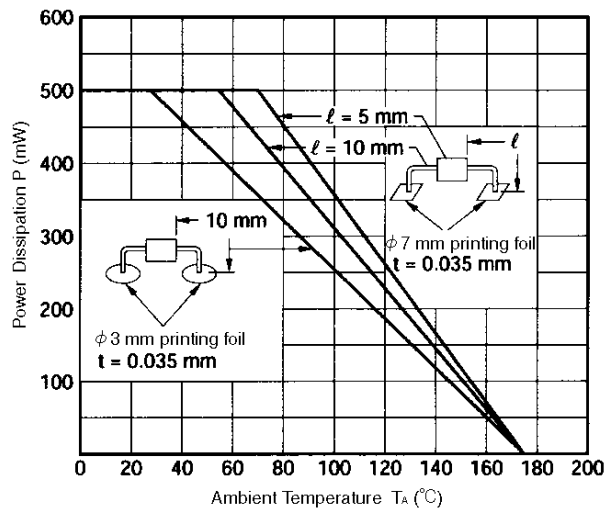


Figure 2. S vs. R_{th} Example of Characteristics

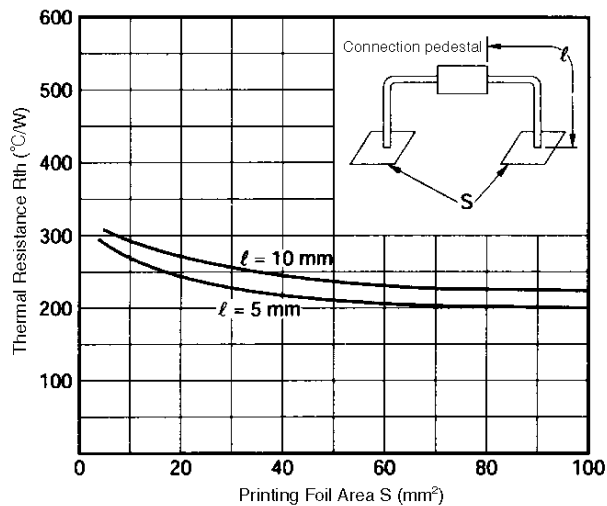
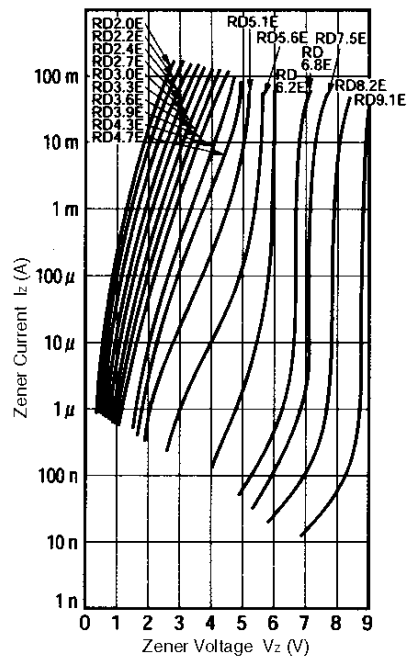
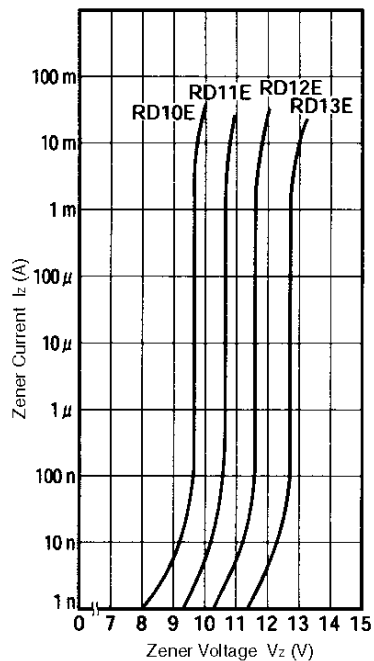


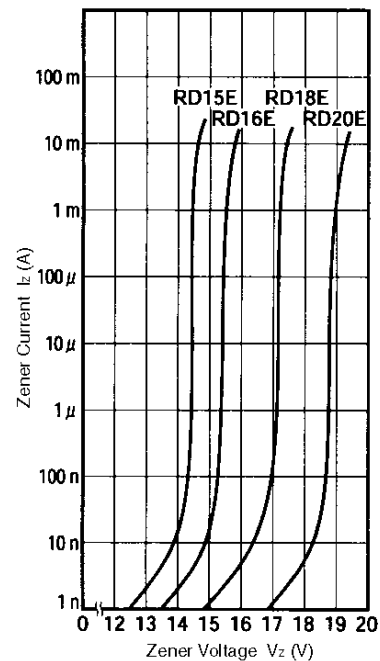
Figure 3. I_z vs. V_z Rating



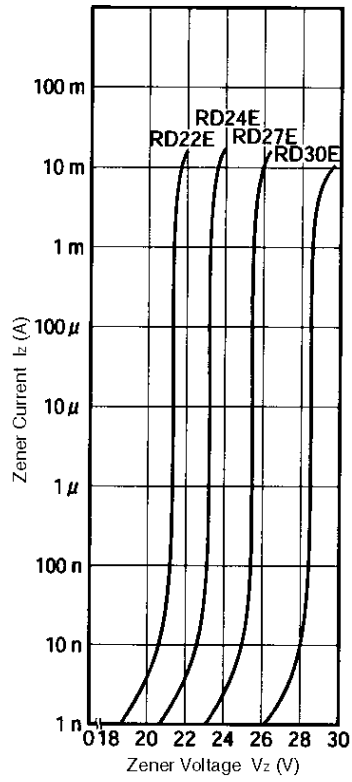
(a)



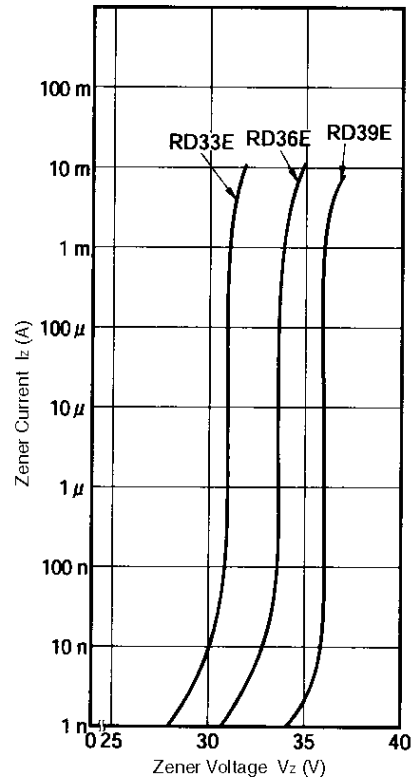
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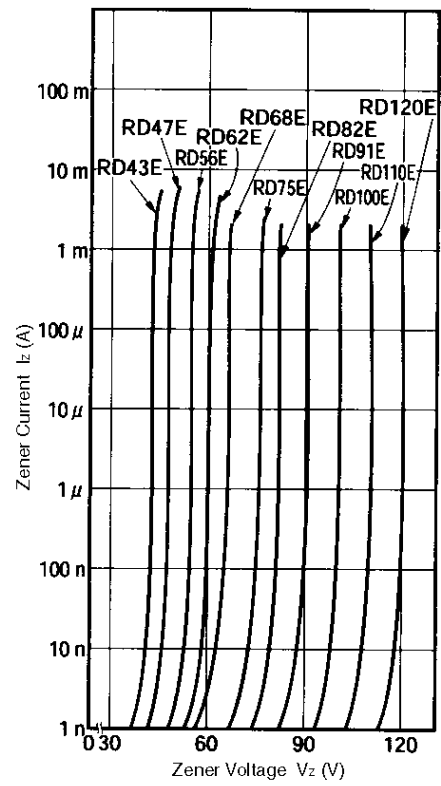
(c)



(d)



(e)



(f)

Figure 4. Z_z vs. I_z Example of Characteristics

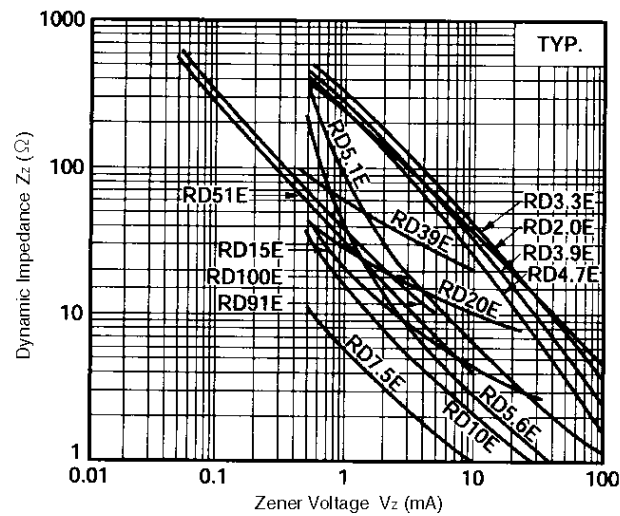
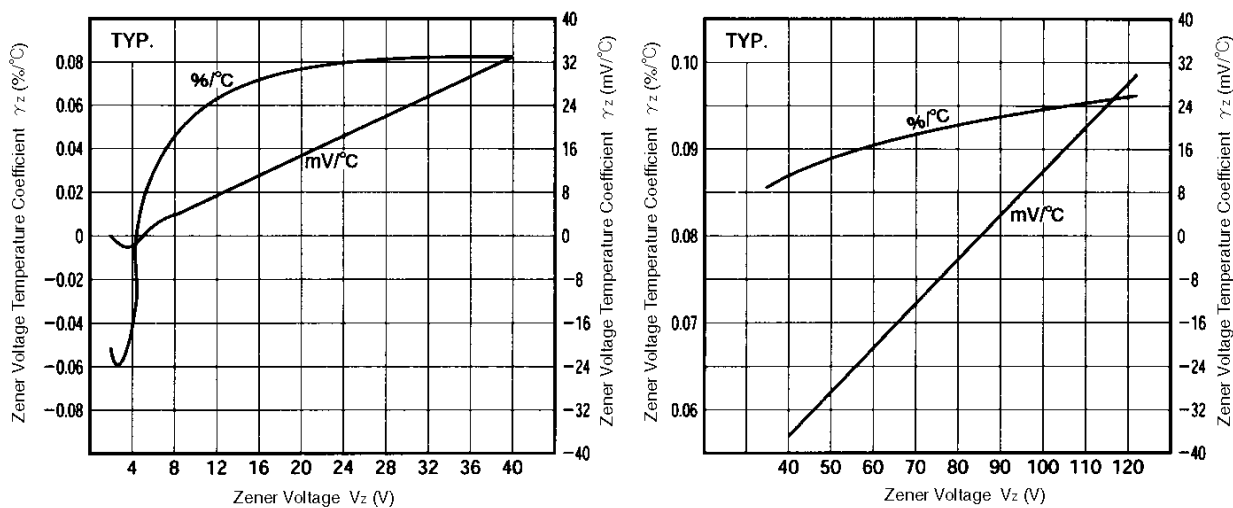


Figure 5. V_z vs. γ_z Example of Characteristics



(a) RD2.0E~RD39E

Figure 6. Surge Reverse Power Rating

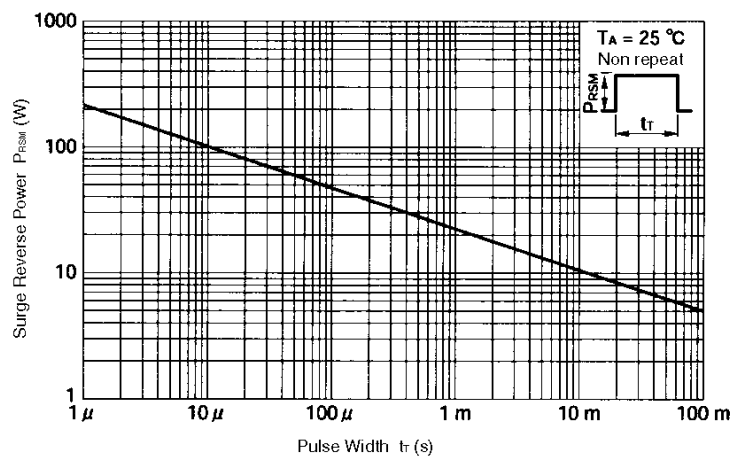
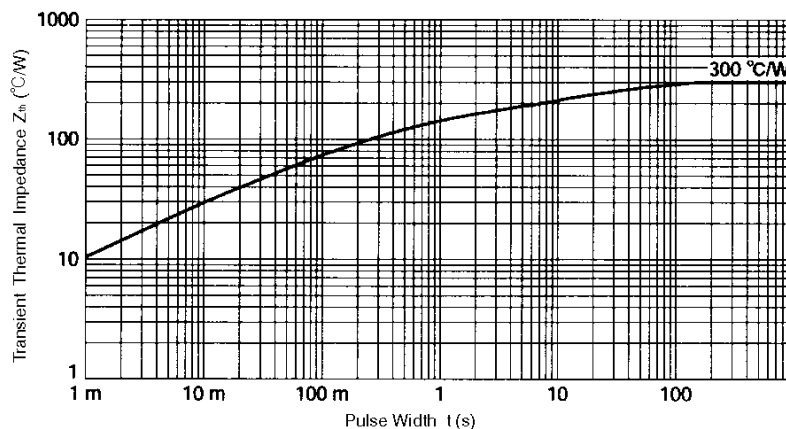


Figure 7. Transient Heat Thermal Impedance



[MEMO]

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